NSN 5961-01-333-7713

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-333-7713 **Inclosure Material:** Ceramic and metal **Overall Length:** Between 0.970 inches and 0.990 inches **Overall Height:** 0.310 inches **Overall Width:** 0.810 inches **End Application:** 5865-01-219-2097 jamming system, communications, general utility **Mounting Facility Quantity:** 2 **Internal Configuration:** Field effect **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 gate to source voltage and 80.0 drain to source voltage and 80.0 drain to gate voltage **Current Rating Per Characteristic:** 6.00 amperes drain current **Power Rating Per Characteristic:** 120.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 3 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:**